

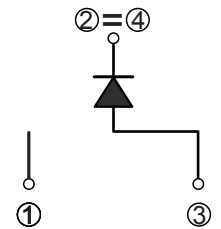
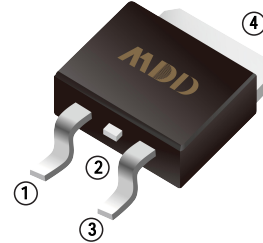
FAST RECOVERY EPI DIODES

TO-252(D-PAK)



FEATURES

- ◆ High frequency operation
- ◆ High surge forward current capability
- ◆ High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- ◆ Guard ring for enhanced ruggedness and long term reliability



MECHANICAL DATA

Case: TO-252 molded plastic body

Terminals: Plated axial leads, solderable per MIL-STD-750, Method 2026

Polarity: Color band denotes cathode end

Mounting Position: Any

Weight: 0.0141 ounce (approx), 0.4 grams (approx)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

CHARACTERISTICS	SYMBOL	MDD MURD820S	MDD MURD840S	MDD MURD860S	UNITS
Maximum repetitive peak reverse voltage	V_{RRM}	200	400	600	V
Maximum RMS voltage	V_{RMS}	140	280	560	V
Maximum DC blocking voltage	V_{DC}	200	400	600	V
Maximum average forward rectified current	$I_{(AV)}$	8			A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	100			A
Maximum instantaneous forward voltage at 8.0A DC	V_F	1.0	1.3	1.6	V
Maximum DC reverse current at rated DC blocking voltage $T_A=25^\circ\text{C}$ $T_A=125^\circ\text{C}$	I_R	10 100			μA
Typical junction capacitance (NOTE 1)	C_J	65			pF
Typical thermal resistance (NOTE 2)	$R_{\theta JA}$	50			$^\circ\text{C}/\text{W}$
Maximum Reverse Recovery Time (Note 3)	T_{rr}	35			ns
Operating junction and storage temperature range	T_J, T_{STG}	-55 to +175			$^\circ\text{C}$

Note: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
2. Thermal resistance from junction to case.
3. Reverse Recovery Test Conditions: $I_F=0.5\text{A}$, $I_R=1\text{A}$, $I_{rr}=0.25\text{A}$.

Rating and Characteristic Curves

Fig.1 Maximum Average Forward Current Rating

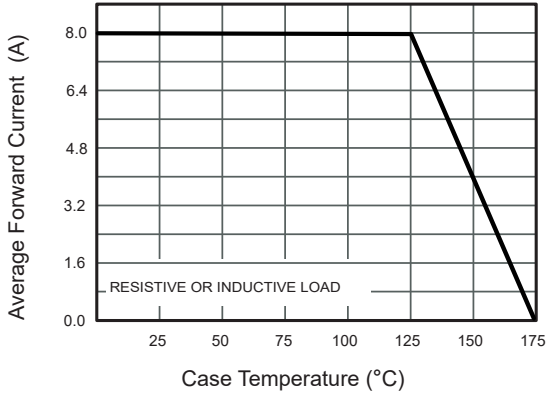


Fig.2 Typical Reverse Characteristics

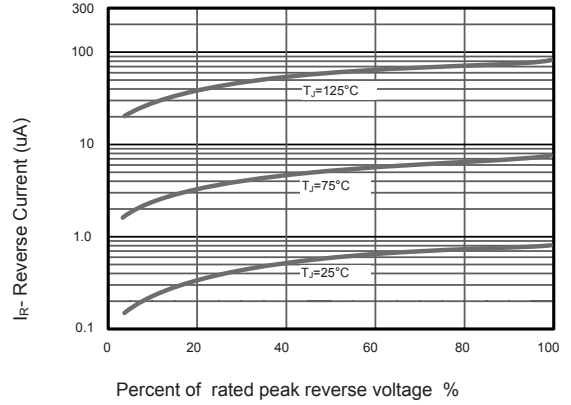


Fig.3 Typical Forward Characteristics

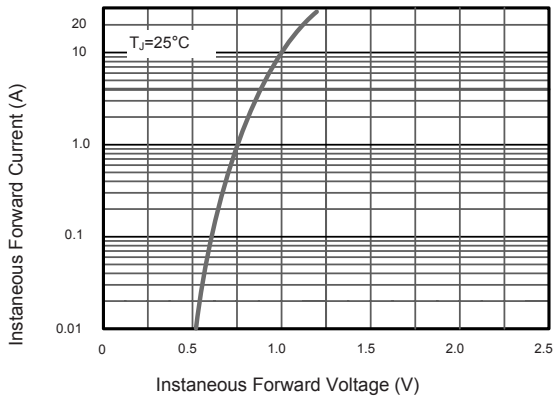


Fig.4 Typical Junction Capacitance

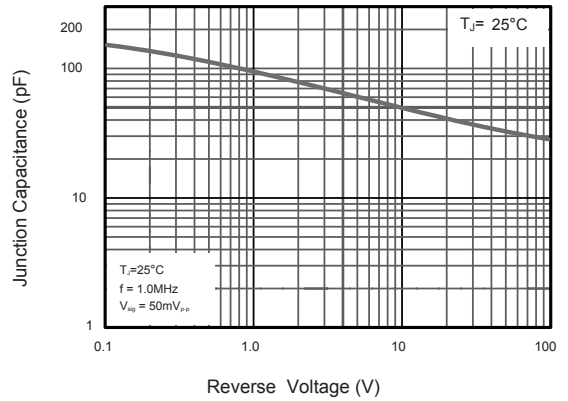


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current

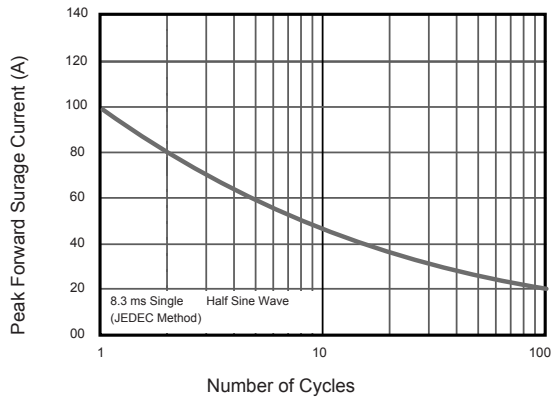
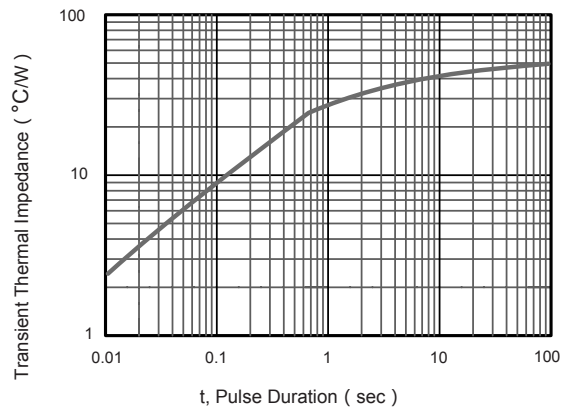


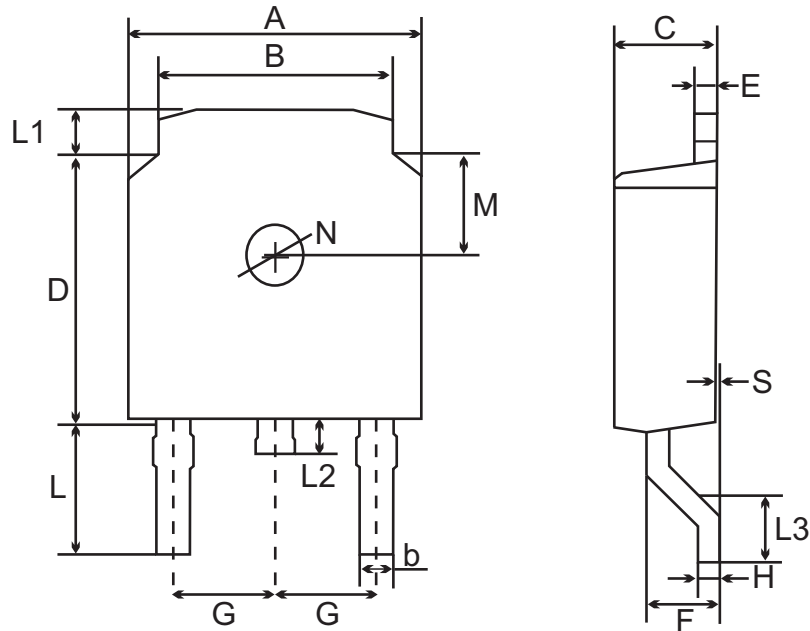
Fig.6- Typical Transient Thermal Impedance



The curve above is for reference only.

Outline Drawing

TO-252(D-PAK) Package Outline Dimensions



TO-252(D-PAK) mechanical data

UNIT		A	B	b	C	D	E	F	G	H	L	L1	L2	L3	S	M	N
mm	max	6.7	5.53	0.86	2.5	6.3	0.6	1.8	2.29 TYPICAL	0.60	3.4	1.2	1.0	1.75	0.15	1.98	1.3
	min	6.3	5.1	0.66	2.1	5.9	0.4	1.3		0.40	2.7	0.8	0.6	1.40	0.0	1.58	1.2

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